

(SMALL-SIGNAL TRANSISTOR)

**2SC5169**

**DUAL TRANSISTOR  
FOR LOW NOISE DIFFERENTIAL AMPLIFY APPLICATION  
SILICON NPN EPITAXIAL TYPE**

**DESCRIPTION**

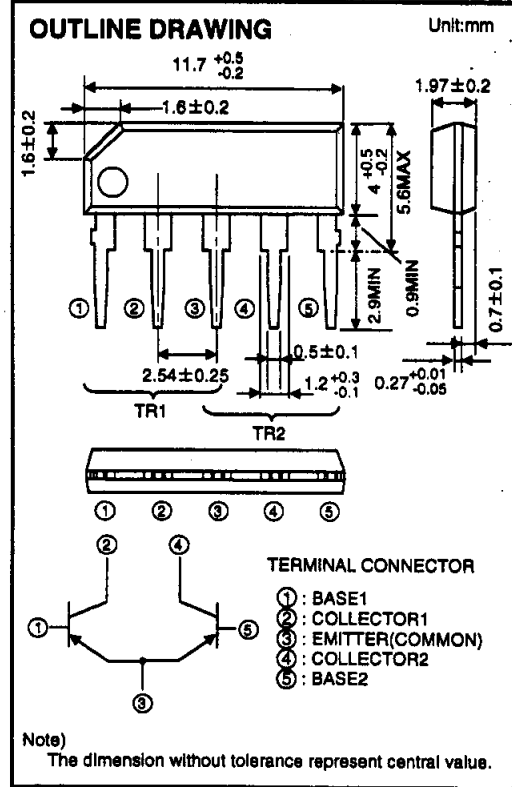
2SC5169 is a silicon NPN epitaxial type transistor. It is designed for low noise differential amplify application.

**FEATURE**

- High  $V_{CEO}$   $V_{CEO}=100V$
- Low noise  $NF=0.5dB$  typ  $NV=100mV$  typ
- High  $h_{FE}$   $h_{FE}=250$  to  $1200$
- Good two elements characteristics  
 $h_{FE1}/h_{FE2}=0.98$  typ  
 $|V_{BE1}-V_{BE2}|=1mV$  typ

**APPLICATION**

For low noise differential amplify application.



**MAXIMUM RATINGS (Ta=25°C)**

Symbol	Parameter	Ratings	Unit
$V_{CBO}$	Collector to Base voltage	100	V
$V_{EBO}$	Emitter to Base voltage	5	V
$V_{CEO}$	Collector to Emitter voltage	100	V
$I_C$	Collector current	50	mA
$P_C$	Collector dissipation (Ta=25°C)	200	mW/unit
$P_T$	Total dissipation (Ta=25°C)	400	mW
$T_j$	Junction temperature	+125	°C
$T_{stg}$	Storage temperature	-55 to +125	°C

**ELECTRICAL CHARACTERISTICS (Ta=25°C)**

Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
$V_{(BR)CEO}$	C to E break down voltage	$I_C=100 \mu A, R_{BE}=\infty$	100			V
$I_{CBO}$	Collector cut off current	$V_{CB}=70V, I_E=0$			0.1	$\mu A$
$I_{EBO}$	Emitter cut off current	$V_{EB}=2V, I_C=0$			0.1	$\mu A$
$I_{CER}$	Collector cut off current	$V_{CE}=100V, R_{BE}=100k\Omega$			10	$\mu A$
$h_{FE}^*$	DC forward current gain	$V_{CE}=6V, I_C=1mA$	250		1200	—
$V_{CE(sat)}$	C to E saturation voltage	$I_C=10mA, I_B=1mA$			0.6	V
$ V_{BE1}-V_{BE2} $	B-E voltage differential	$V_{CE}=6V, I_C=1mA$		1	10	mV
$h_{FE1}/h_{FE2}$	DC forward current gain ratio	$V_{CE}=6V, I_C=1mA$	0.8	0.98	1.0	—
$f_T$	Gain band width product	$V_{CE}=6V, I_E=-1mA$		150		MHz
$C_{ob}$	Collector output capacitance	$V_{CB}=6V, I_E=0, f=1MHz$		1.8		pF
NF	Noise figure	$V_{CE}=6V, I_E=-0.1mA, f=1kHz, R_G=10k\Omega$		0.5		dB
NV	Low frequency broadband noise voltage	$V_{CE}=10V, I_E=-1mA, R_G=100k\Omega, G_v=80dB$ , (Refer to test circuit)		100		mV
NVM			effective value		0.5	
	peaked value					

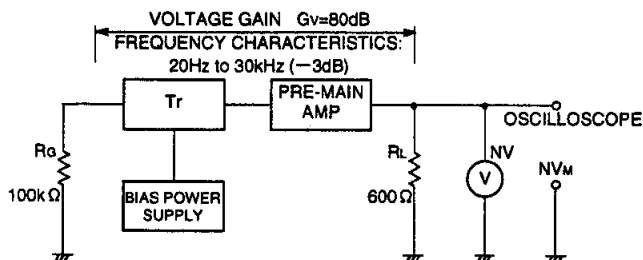
\* : It shows  $h_{FE}$  (element 1) classification in right table.

Item	F	G	H
$h_{FE}$	250 to 500	400 to 800	600 to 1200

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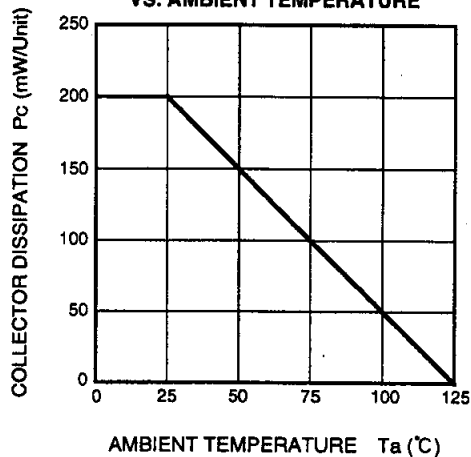
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LOW FREQUENCY WIDE BAND  
NOISE VOLTAGE TEST CIRCUIT

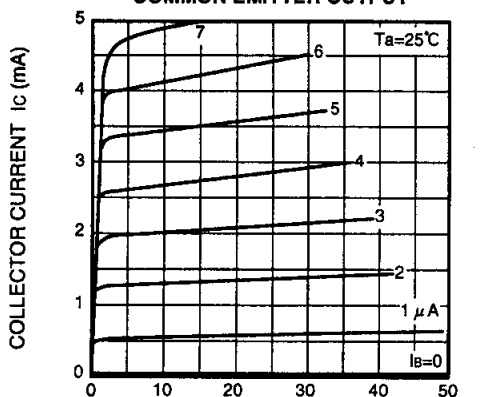


TYPICAL CHARACTERISTICS

COLLECTOR DISSIPATION  
VS. AMBIENT TEMPERATURE

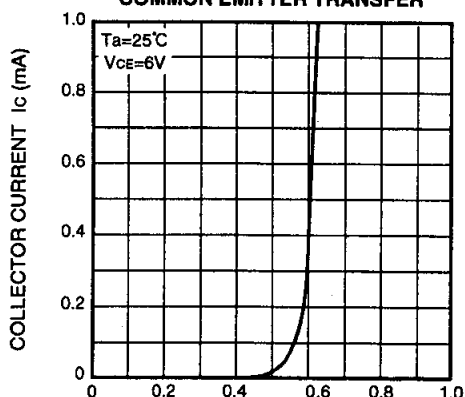


COMMON EMITTER OUTPUT



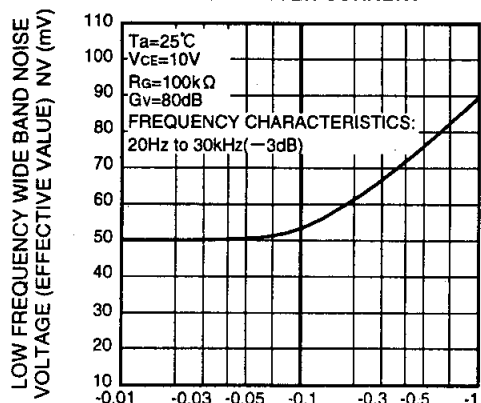
COLLECTOR TO EMITTER VOLTAGE  $V_{CE}(V)$

COMMON EMITTER TRANSFER



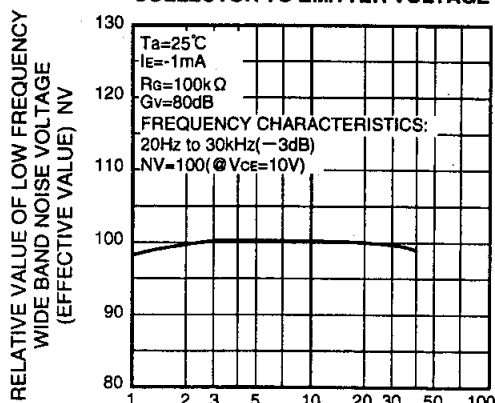
BASE TO EMITTER VOLTAGE  $V_{BE}(V)$

LOW FREQUENCY WIDE BAND  
NOISE VOLTAGE (EFFECTIVE VALUE)  
VS. EMITTER CURRENT



EMITTER CURRENT  $I_E$  (mA)

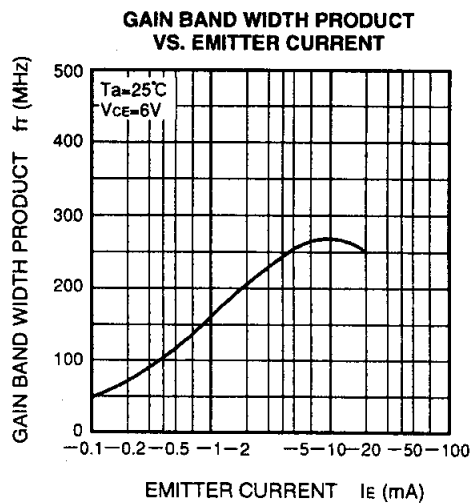
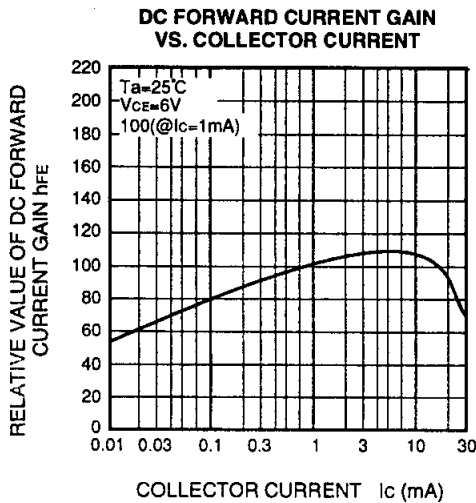
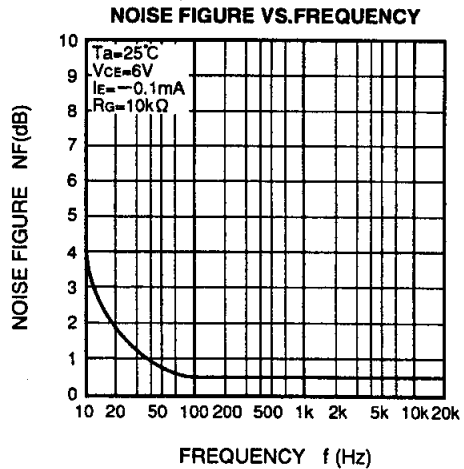
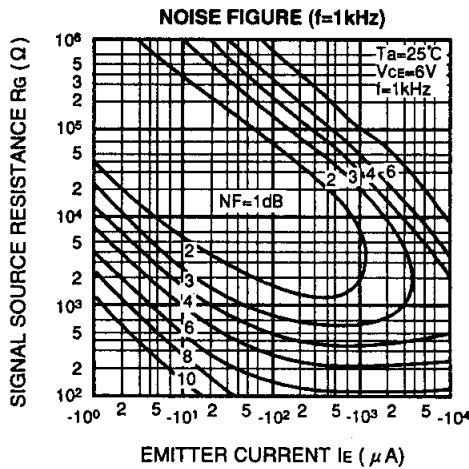
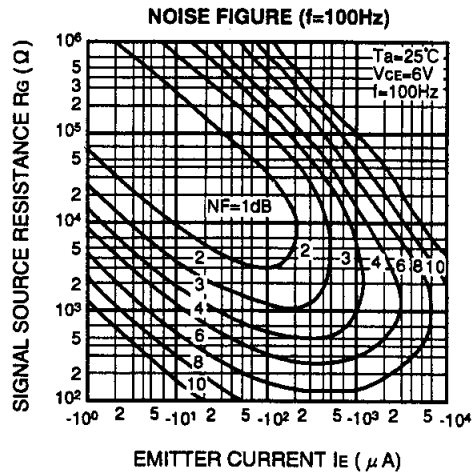
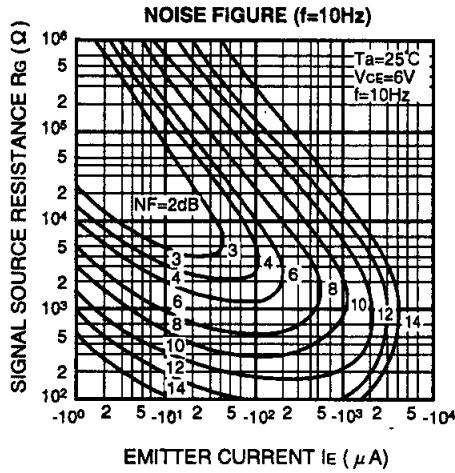
LOW FREQUENCY WIDE BAND  
NOISE VOLTAGE (EFFECTIVE) VS.  
COLLECTOR TO EMITTER VOLTAGE



COLLECTOR TO EMITTER VOLTAGE  $V_{CE}(V)$

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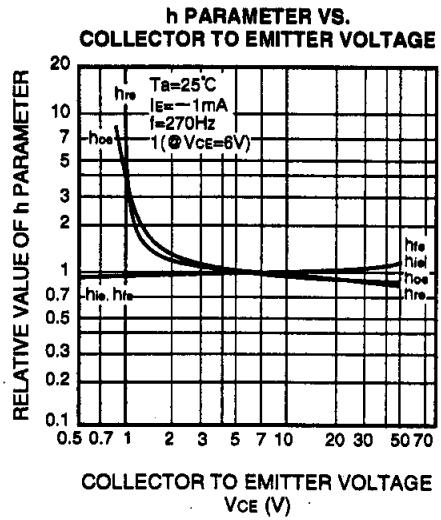
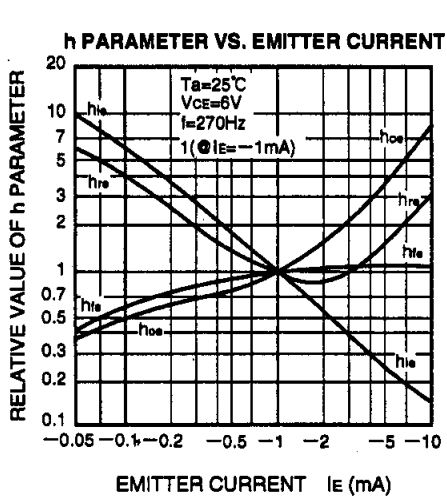
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**COMMON EMITTER h PARAMETER (TYPICAL VALUE)**

Symbol	Parameter	Test conditions	Limits	Unit
$h_{ie}$	Closed loop small signal input impedance	$T_a=25^\circ\text{C}$ $V_{CE}=6\text{V}$ $I_E=-1\text{mA}$ $f=270\text{Hz}$	18	k $\Omega$
$h_{re}$	Open loop small signal reverse voltage amplification factor		0.08	$\times 10^{-3}$
$h_{fe}$	Closed loop small signal forward current amplification factor		600	—
$h_{oe}$	Open loop small signal output admittance		10	$\mu\text{S}$

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